

♦ STRUCTURE

Silicon Monolithic Integrated Circuit

♦ PRODUCT

I<sup>2</sup>C BUS Serial EEPROMs

♦ SERIES

ADVANTAGE SERIES
BR24C□□ family

♦ FAMILY
♦ TYPE

Supply voltage 1.8V ~ 5.5V/Opreating temperature −40°C ~ +85°Ctype

**♦ PART NUMBER** 

BR24C □ □ -10 □ U-1.8

PART NUMBER	PACKAGE	DENSITY
BR24C01A -10SU-1.8		1Kbit
BR24C02N -10SU-1.8		2Kbit
BR24C04N -10SU-1.8	8−lead	4Kbit
BR24C08AN -10SU-1.8	JEDECSOIC	8Kbit
BR24C16AN -10SU-1.8		16Kbit
BR24C32AN -10SU-1.8		32Kbit
BR24C01A -10TU-1.8		1Kbit
BR24C02 -10TU-1.8		2Kbit
BR24C04 -10TU-1.8	8-lead	4Kbit
BR24C08A -10TU-1.8	TSSOP	8Kbit
BR24C16A -10TU-1.8		16Kbit
BR24C32A -10TU-1.8		32Kbit

Two wire serial interface

Endurance: 1,000,000 erase/write cycles

Data retention : 100years Intial Data FFh in all address

#### **♦ ABSOLUTE MAXIMUM RATING**

Parameter	Symbol	Rating	Unit
Operating Temperature	Topr	-40~85	°C
Storage Temperature	Tstg	-65 <b>~</b> 125	°C
Voltage on Any Pin with Respect to Ground	-	-0.3∼Vcc+0.3	٧
Maximum Operating Voltage	Vcc	-0.3~6.5	V

## ♦ POWER DISSIPATION (Ta=25°C)

PACKAGE	Rating	Unit	
8-lead JEDECSOIC	450 *1	mW	
8-lead TSSOP	330 *2	mW	

<sup>\*</sup> Degradation is done at 4.5mW/°C(\*1), 3.3mW/°C(\*2)for operation above 25°C



## **♦ DC OPERATING CHARACTERISTICS**

BR24C01A/02/04/08A/16A. Unless otherwise specified, Vcc=1.8V to 5.5V, Ta=-40 $^{\circ}$ C to 85 $^{\circ}$ C

Parameter	Symbol	Min	Max	Unit	Test Conditions
Supply Current Vcc=5.0V	Lcci	-	1.0	mA	READ at 100 kHz
Supply Current Vcc=5.0V	I <sub>CC2</sub>	-	3.0	mA	WRITE at 100 kHz
Standby Current Vcc=1.8V	I <sub>SB1</sub>	-	3.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND
Standby Current Vcc=2.5V	I <sub>SB2</sub>	-	4.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND
Standby Current Vcc=2.7V	I <sub>SB3</sub>	-	4.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND
Standby Current Vcc=5.0V	I <sub>SB4</sub>	-	18.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND
Input Leakage Current	i <sub>u</sub>	-	3.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND
Output Leakage Current	l <sub>Lo</sub>	-	3.0	μА	V <sub>out</sub> =V <sub>cc</sub> or GND
	V <sub>IL</sub>	-	Vccx0.3	V	2.5V≦Vcc≦5.5V
Input Low Level		-	Vccx0.2	'	1.8V≦Vcc<2.5V
	V	Vccx0.7	-	,,	2.5V≦Vcc≦5.5V
Input High Level	V <sub>BH</sub>	Vccx0.8	-	\ \ \ \	1.8V≦Vcc<2.5V
Output Low Level Vcc=3.0V	V <sub>OL1</sub>	-	0.4	V	l <sub>OL</sub> =2.1mA
Output Low Level Vcc=1.8V	V <sub>OL2</sub>	-	0.2	٧	I <sub>OL</sub> =0.15mA

#### **♦ AC OPERATING CHARACTERISTICS**

BR24C01A/02/04/08A/16A.Unless otherwise specified,Vcc=1.8V to 5.5V, Ta=-40°C to 85°C

		1.8	.8V 2.5 <sup>1</sup>		7V,5.0V	
Parameter	Symbol	Min	Max	Min	Max	Unit
Clock Frequency, SCL	f <sub>SCL</sub>	-	100	-	400	kHz
Clock Pulse Width Low	t <sub>LOW</sub>	4.7	-	1.2	-	μs
Clock Pulse Width High	t <sub>HGH</sub>	4.0	-	0.6	-	μs
Noise Suppression Time	t <sub>i</sub>		100	-	50	ns
Clock Low to Data Out Valid	t <sub>AA</sub>	0.1	4.5	0.1	0.9	μs
Time the bus must be free before a new transmission can start	t <sub>BUF</sub>	4.7	-	1.2	-	μs
Start Hold Time	t <sub>HD.STA</sub>	4.0	-	0.6	-	μs
Start Setup Time	t <sub>SU.STA</sub>	4.7	-	0.6	-	μs
Data In Hold Time	t <sub>HD.DAT</sub>	0	-	0	-	μs
Data In Setup Time	t <sub>SU.DAT</sub>	200	-	100	-	ns
Inputs Rise Time *1	t <sub>R</sub>	-	1.0	-	0.3	μs
Inputs Fall Time *1	t <sub>F</sub>	-	300	-	300	ns
Stop Setup Time	t <sub>su.sTo</sub>	4.7	-	0.6	-	μs
Data Out Hold Time	t <sub>oH</sub>	100	-	50	-	ns
Write Cycle Time	t <sub>we</sub>	-	5		5	ms
Endurance *1 5.0V, 25°C	Endurance	1M	-	1M	_	Write Cycles

\*1 Not 100% TESTED

R24C32A Unless otherwise specified, Vcc=1.8V to 5.5V, Ta=-40°C to 85°C

BR24C32A Unless otherwise specified,Vcc=1.8V to 5.5V, Ta=-40°C to 85°C									
Parameter	Symbol	Min	Max	Unit	Test Conditions				
Supply Current Vcc=5.0V	I <sub>CC1</sub>	-	1.0	mA	READ at 400 kHz				
Supply Current Vcc=5.0V	I <sub>CC2</sub>	-	3.0	mA	WRITE at 400 kHz				
Standby Current Vcc=1.8V	I <sub>SB1</sub>	-	1.0	μΑ	V <sub>IN</sub> =V <sub>CC</sub> or GND				
Standby Current Vcc=2.5V	I <sub>SB2</sub>	-	2.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND				
Standby Current Vcc=2.7V	I <sub>SB3</sub>	-	2.0	μΑ	V <sub>IN</sub> =V <sub>CC</sub> or GND				
Standby Current Vcc=5.0V	I <sub>SB4</sub>	-	6.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND				
Input Leakage Current	Ę,	-	3.0	μА	V <sub>IN</sub> =V <sub>CC</sub> or GND				
Output Leakage Current	I <sub>LO</sub>	-	3.0	μА	V <sub>OUT</sub> =V <sub>CC</sub> or GND				
	V <sub>B.</sub>	_	Vccx0.3		2.5V≦Vcc≦5.5V				
Input Low Level		-	Vcc×0.2	\	1.8V≦Vcc<2.5V				
	.,	Vcc×0.7	-	Ī.,	2.5V≦Vcc≦5.5V				
Input High Level	V <sub>IH</sub>	Vccx0.8	-	V	1.8V≦Vcc<2.5V				
Output Low Level Vcc=3.0V	Voli	-	0.4	V	I <sub>OL</sub> =2.1mA				
Output Low Level Vcc=1.8V	Volz		0.2	٧	I <sub>OL</sub> =0.15mA				

OThis product is not designed for protection against radioactive rays.

#### BR24C32A.Unless otherwise specified,Vcc=1.8V to 5.5V, Ta=-40°C to 85°C

D	C	1.	8V	2.5V,2	7V,5.0V	Unit
Parameter	Symbol	Min	Мах	Min	Max	Unit
Clock Frequency, SCL	f <sub>SCL</sub>	-	100	-	400	kHz
Clock Pulse Width Low	t <sub>LOW</sub>	4.7	-	1.3	-	μs
Clock Pulse Width High	t <sub>HIGH</sub>	4.0	-	0.6	-	μs
Noise Suppression Time	tı	-	100	-	50	ns
Clock Low to Data Out Valid	t <sub>AA</sub>	0.1	4.5	0.1	0.9	μs
Time the bus must be free before a new transmission can start	t <sub>BUF</sub>	4.7	-	1.3	-	μs
Start Hold Time	4 <sub>HD.STA</sub>	4.0	-	0.6	-	μs
Start Setup Time	t <sub>SU.STA</sub>	4.7	-	0.6	-	μs
Data In Hold Time	t <sub>HD.DAT</sub>	0	-	0		μs
Data In Setup Time	t <sub>SU.DAT</sub>	200	-	100	-	ns
Inputs Rise Time *1	t <sub>R</sub>	-	1.0	-	0.3	μs
Inputs Fall Time *1	t <sub>F</sub>	-	300	-	300	ns
Stop Setup Time	t <sub>su.sto</sub>	4.7	-	0.6	-	μs
Data Out Hold Time	t <sub>oH</sub>	100	-	50	-	ns
Write Cycle Time	t <sub>wr</sub>	-	5	-	5	ms
Endurance *1 5.0V, 25℃	Endurance	1M	-	1M	-	Write Cycles

\*1 Not 100% TESTED

## ♦ BLOCK DIAGRAM

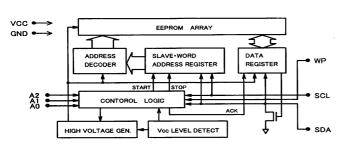


Fig.-1 BLOCK DIAGRAM

♦ PIN No., PIN NAME

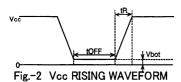
PIN No.	PIN NAME
1	A0
2	A1
3	A2
4	GND
5	SDA
6	SCL
7	WP
8	Vcc



#### **ONOTES FOR POWER SUPPLY**

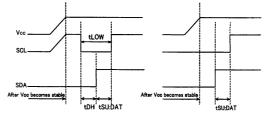
Vcc rises through the low voltage region in which internal circuit of IC and the controller are unstable, so that device may not work properly due to an incomplete reset of internal circuit. To prevent this, the device has the feature of P.O.R. and LVCC. In the case of power up, keep the following conditions to ensure functions of P.O.R. and LVCC.

- 1. It is necessary to be "SDA='H'" and "SCL='L' or 'H'".
- 2. Follow the recommended conditions of tR, tOFF, Vbot for the function of P.O.R. during power up.



◇RECOMMENDED CONDITIONS OF tR, tOFF, Vbot						
tR	tOFF	Vbot				
Below 10ms	elow 10ms Above 10ms					
Below 100ms	Above 10ms	Below 0.2V				

- Prevent SDA and SCL from being "High-Z".
   In case that condition 1. and/or 2. cannot be met, take following actions.
  - A) Unable to keep condition 1.
    - (SDA is "LOW" during power up.)
    - → Control SDA ,SCL to be "HIGH" as Fig.-3(a), 3(b).
  - B) Unable to keep condition 2.
    - → After power becomes stable, execute software reset.



- Fig.-3(a) SCL='H' and SDA='L'
- Fig.-3(b) SCL='L' and SDA='L'

- C) Unable to keep both conditions 1 and 2.
  - → Follow the instruction A first, then the instruction B.

#### **CAUTIONS ON USE**

(1) Absolute maximum ratings

If the absolute maximum ratings such as impressed voltage and action temperature range and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.

(2) GND electric potential

Set the voltage of GND terminal lowest at any action condition. Make sure that each terminal voltage is lower than that of GND terminal.

(3) Thermal design

In consideration of permissible loss in actual use condition, carry out heat design with sufficient margin.

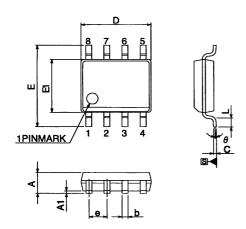
(4) Terminal to terminal shortcircuit and wrong packaging

When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of shortcircuit between LSI terminals and terminals and power source, terminal and GND owing to foreign matter, LSI may be destructed.

(5) Use in a strong electromagnetic field may cause malfunction, therefore, evaluated design sufficiently.



## **♦ PHYSICAL DIMENSION**

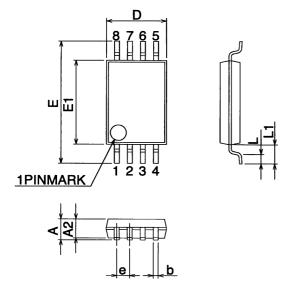


Notes

1. This drawing is subject to change without notice.

2.Body dimensions do not include mold flash or protrusion, or gate burns.
3.Reference JEDEC MS-012 variation AA.

Fig-4 8-lead JEDECSOIC Package Outline



## Notes

1. This drawing is subject to change without notice.

2.Body dimensions do not include mold flash or protrusion, or gate burns.
3.Reference MO-153

Fig-5 8-lead TSSOP Package Outline

♦ 8-lead JEDECSOIC Package Size Data

Symbol		mm		inches		
Symbol	Тур.	Min.	Max.	Тур.	Min.	Max.
Α	-	1.35	1.75	_	0.053	0.069
A1	1	0.10	0.25		0.004	0.010
b	1	0.31	0.51	-	0.012	0.020
С	1	0.17	0.25	-	0.007	0.010
D	1	4.80	5.00	-	0.189	0.197
	1.27		_	0.050		
е	BSC			BSC	-	_
E	1	5.79	6.20	_	0.228	0.244
E1	1	3.81	3.99	-	0.150	0.157
L	1	0.40	1.27	-	0.016	0.050
θ	1	0°	8°	-	0°	8°

♦ 8-lead TSSOP Package Size Data

Symbol		mm			inches			
Symbol	Тур.	Min.	Max.	Тур.	Min.	Max.		
Α	_	-	1.20		_	0.047		
A2	1.00	0.80	1.05	0.039	0.031	0.041		
b	1	0.19	0.30	-	0.007	0.012		
D	3.00	2.90	3.10	0.118	0.114	0.122		
е	0.65	-	_	0.025	1	-		
	BSC							
E	6.40		_	0.252				
	BSC	_	_	0.252	_	_		
E1	4.40	4.30	4.50	0.173	0.169	0.177		
L	0.60	0.45	0.75	0.023	0.017	0.030		
L1	1.00			0.039				
"	REF		_	0.039	_	_		

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